# NSN 5961-00-470-5361

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-00-470-5361

# Inclosure Material:

Metal

**Overall Length:** 

1.252 inches

# **Overall Height:**

Between 0.250 inches and 0.340 inches

# **Overall Width:**

0.700 inches

# **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-66

Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

300.0 breakdown voltage, collector-to-emitter, base open

# **Current Rating Per Characteristic:**

2.00 amperes source cutoff current and 1.00 amperes source cutoff current

# **Power Rating Per Characteristic:**

35.0 watts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

# **Terminal Type And Quantity:**

1 case and 2 pin

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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